IN THE CLAIMS

Please amend the claims as follows:

- (Original) A method of checking data in a two dimensional pattern, comprising: identification of a region within the pattern that surrounds at least one feature in the pattern;
- subtraction of the feature from within the region, leaving a two dimensional ring-like region; and
 - analyzing optical behavior within the ring-like region to predict optical interactions.
- 2. (Original) The method of claim 1, wherein identification of a region within the pattern includes sizing up the feature by a given distance.
- (Original) The method of claim 2, wherein sizing up the feature by a given distance includes sizing up the feature by an optical ambit distance.
- (Original) The method of claim 1, wherein analyzing of optical behavior within the ringlike region includes three dimensional optical analysis affecting patterns within the two dimensional ring-like region.
- (Original) The method of claim 1, wherein analyzing of optical behavior includes predicting optical interference that forms at least one additional feature in a given lithographic process.
- (Original) The method of claim 5, wherein analyzing of optical behavior includes predicting a location of an additional feature in the given lithographic process.
- (Original) The method of claim 6, wherein analyzing of optical behavior includes predicting a size and shape of the additional feature in the given lithographic process.

- (Original) A method of forming a reticle, comprising:
 organizing data into a two dimensional pattern of features;
 - checking the data, including:

identification of a region within the pattern that surrounds at least one feature in the pattern;

subtraction of the feature from within the region, leaving a two dimensional ringlike region;

analyzing optical behavior within the ring-like region to identify interaction regions;

organizing data into at least one modifying feature located within at least one interaction region; and

printing the two dimensional pattern of features and the at least one modifying feature onto a reticle substrate.

- (Original) The method of claim 8, wherein organizing data into at least one modifying feature includes organizing data into at least one sub printing lithographic aperture.
- 10. (Original) The method of claim 8, wherein identification of a region within the pattern includes sizing up the feature by a given distance.
- 11. (Original) The method of claim 10, wherein sizing up the feature by a given distance includes sizing up the feature by an optical ambit distance.
- 12. (Original) The method of claim 10, wherein analyzing of optical behavior includes predicting optical interference that forms at least one additional feature in a given lithographic process.
- (Original) The method of claim 12, wherein analyzing of optical behavior includes predicting a location of an additional feature in the given lithographic process.

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- 14. (Original) The method of claim 13, wherein analyzing of optical behavior includes predicting a size and shape of the additional feature in the given lithographic process.
- (Original) A method of forming a pattern of features on a semiconductor substrate: organizing data into a two dimensional pattern of features;

checking the data, including:

identification of a region within the pattern that surrounds at least one feature in the pattern;

subtraction of the feature from within the region, leaving a two dimensional ringlike region:

analyzing optical behavior within the ring-like region to identify interaction regions;

organizing data into at least one modifying feature located within at least one interaction region;

printing the two dimensional pattern of features and the at least one modifying feature onto a reticle substrate; and

forming the two dimensional pattern of features on the semiconductor substrate wherein the modifying feature substantially prevents printing of unwanted features.

- 16. (Original) The method of claim 15, wherein organizing data into at least one modifying feature includes organizing data into at least one sub printing lithographic aperture.
- 17. (Original) The method of claim 15, wherein identification of a region within the pattern includes sizing up the feature by a given distance.
- 18. (Original) The method of claim 17, wherein sizing up the feature by a given distance includes sizing up the feature by an optical ambit distance.

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19. (Original) The method of claim 15, wherein forming the two dimensional pattern of features on the semiconductor substrate includes photolithography with a UV wavelength energy source.

- (Original) The method of claim 15, wherein forming the two dimensional pattern of
 features on the semiconductor substrate includes photolithography with an X-ray wavelength
 energy source.
- 21. (Currently Amended) A machine-readable medium with instructions stored thereon, the instructions when executed operable to cause:

identification of a region within [[the]] a pattern that surrounds at least one feature in the pattern;

subtraction of the feature from within the region, leaving a two dimensional ring-like region; and

analyzing of optical behavior within the ring-like region to predict optical interactions.

- 22. (Original) The machine-readable medium of claim 21, wherein identification of a region within the pattern includes sizing up the feature by a given distance.
- 23. (Original) The machine-readable medium of claim 22, wherein sizing up the feature by a given distance includes sizing up the feature by an optical ambit distance.
- 24. (Original) The machine-readable medium of claim 21, wherein analyzing of optical behavior includes predicting optical interference that forms at least one additional feature in a given lithographic process.
- (Original) The machine-readable medium of claim 24, wherein analyzing of optical behavior includes predicting a location of an additional feature in the given lithographic process.

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- 26. (Original) The machine-readable medium of claim 25, wherein analyzing of optical behavior includes predicting a size and shape of the additional feature in the given lithographic process.
- 27. (Currently Amended) A pattern generating system, comprising:
- a memory, containing instructions thereon, the instructions when executed operable to cause:
- identification of a region within [[the]] \underline{a} pattern that surrounds at least one feature in the pattern;
- subtraction of the feature from within the region, leaving a two dimensional ringlike region; and
- analyzing of optical behavior within the ring-like region to predict optical interactions.
- 28. (Original) The pattern generating system of claim 27, wherein identification of a region within the pattern includes sizing up the feature by a given distance.
- 29. (Original) The pattern generating system of claim 28, wherein sizing up the feature by a given distance includes sizing up the feature by an optical ambit distance.
- 30. (Original) The pattern generating system of claim 27, wherein analyzing of optical behavior includes predicting optical interference that forms at least one additional feature in a given lithographic process.
- (Original) The pattern generating system of claim 30, wherein analyzing of optical behavior includes predicting a location of an additional feature in the given lithographic process.

32. (Original) The pattern generating system of claim 31, wherein analyzing of optical behavior includes predicting a size and shape of the additional feature in the given lithographic process.